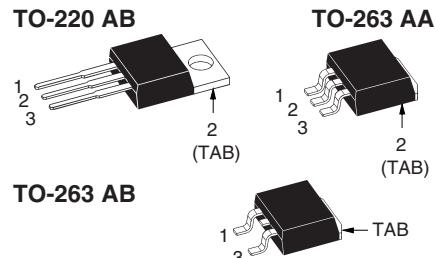
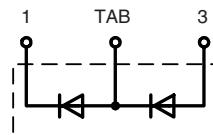


## Phase-leg Rectifier Diode

**V<sub>RRM</sub> = 800/1200 V**  
**I<sub>F(RMS)</sub> = 2x17 A**  
**I<sub>F(AV)M</sub> = 2x11 A**

V <sub>RSM</sub>	V <sub>RRM</sub>	TO-220 AB	TO-263 AA	TO-263AB
V	V	Type		
900	800	DSP 8-08A	DSP 8-08AS	DSP 8-08S
1300	1200	DSP 8-12A	DSP 8-12AS	DSP 8-12S



1 = Cathode, 2 = Anode/Cathode, 3 = Anode  
TAB = Anode/Cathode

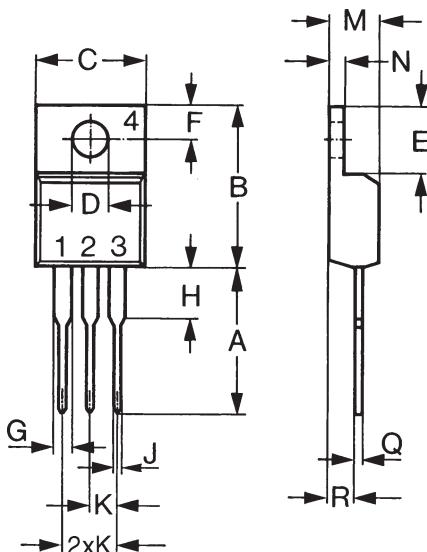
Symbol	Conditions	Maximum Ratings		
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	17	A	
I <sub>F(AV)M</sub>	T <sub>case</sub> = 100°C; 180° sine	11	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine	100	A	
	t = 8.3 ms (60 Hz), sine	110	A	
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine	90	A	
	t = 8.3 ms (60 Hz), sine	100	A	
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine	50	A <sup>2</sup> s	
	t = 8.3 ms (60 Hz), sine	50	A <sup>2</sup> s	
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine	41	A <sup>2</sup> s	
	t = 8.3 ms (60 Hz), sine	42	A <sup>2</sup> s	
T <sub>VJ</sub>		-40...+180	°C	
T <sub>VJM</sub>		180	°C	
T <sub>stg</sub>		-40...+150	°C	
M <sub>d</sub> <sup>1)</sup>	Mounting torque	0.4...0.6	Nm	
Weight	TO-263/TO-220	2/4	g	

Symbol	Conditions	Characteristic Values		
I <sub>R</sub>	T <sub>VJ</sub> = 25°C    V <sub>R</sub> = V <sub>RRM</sub>	≤	5	μA
V <sub>F</sub>	I <sub>F</sub> = 7 A; T <sub>VJ</sub> = 25°C	≤	1.15	V
V <sub>To</sub>	For power-loss calculations only	0.8	V	
r <sub>T</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	40	mΩ	
R <sub>thJC</sub>	DC current	3.5	K/W	
R <sub>thCH</sub> <sup>1)</sup>	DC current (with heatsink compound)	typ.	0.5	K/W
a	Maximum allowable acceleration	100	m/s <sup>2</sup>	

<sup>1)</sup> TO-220 only

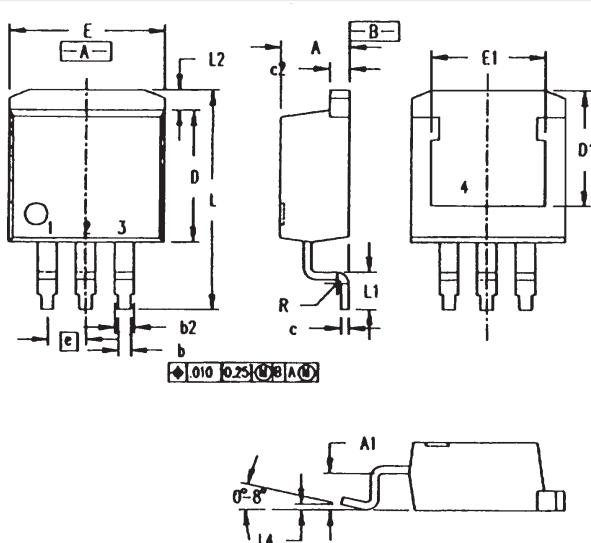
Data according to IEC 60747 and refer to a single diode unless otherwise stated.

## TO-220 AB Outline



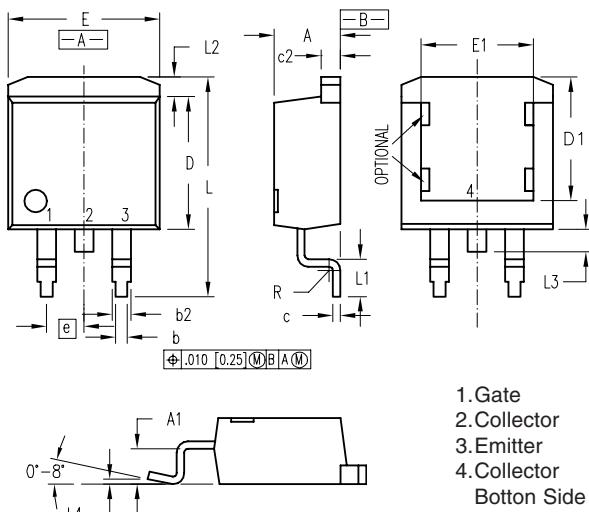
Dim.	Millimeter Min. Max.	Inches Min. Max.
A	12.70 13.97	0.500 0.550
B	14.73 16.00	0.580 0.630
C	9.91 10.66	0.390 0.420
D	3.54 4.08	0.139 0.161
E	5.85 6.85	0.230 0.270
F	2.54 3.18	0.100 0.125
G	1.15 1.65	0.045 0.065
H	2.79 5.84	0.110 0.230
J	0.64 1.01	0.025 0.040
K	2.54 BSC	0.100 BSC
M	4.32 4.82	0.170 0.190
N	1.14 1.39	0.045 0.055
Q	0.38 0.56	0.015 0.022
R	2.29 2.79	0.090 0.110

## TO-263 AA Outline



Dim.	Millimeter Min. Max.	Inches Min. Max.
A	4.06 4.83	.160 .190
A1	2.03 2.79	.080 .110
b	0.51 0.99	.020 .039
b2	1.14 1.40	.045 .055
c	0.46 0.74	.018 .029
c2	1.14 1.40	.045 .055
D	8.64 9.65	.340 .380
D1	7.11 8.13	.280 .320
E	9.65 10.29	.380 .405
E1	6.86 8.13	.270 .320
e	2.54 BSC	.100 BSC
L	14.61 15.88	.575 .625
L1	2.29 2.79	.090 .110
L2	1.02 1.68	.040 .066
L4	0 0.38	0 .015
R	0.46 0.74	.018 .029

## TO-263 AB Outline



- 1. Gate
- 2. Collector
- 3. Emitter
- 4. Collector Bottom Side

Dim.	Millimeter Min. Max.	Inches Min. Max.
A	4.06 4.83	.160 .190
A1	2.03 2.79	.080 .110
b	0.51 0.99	.020 .039
b2	1.14 1.40	.045 .055
c	0.46 0.74	.018 .029
c2	1.14 1.40	.045 .055
D	8.64 9.65	.340 .380
D1	8.00 8.89	.315 .350
E	9.65 10.29	.380 .405
E1	6.22 8.13	.245 .320
e	2.54 BSC	.100 BSC
L	14.61 15.88	.575 .625
L1	2.29 2.79	.090 .110
L2	1.02 1.68	.040 .066
L3	1.27 1.78	.050 .070
L4	0 0.20	0 .008
R	0.46 0.74	.018 .029

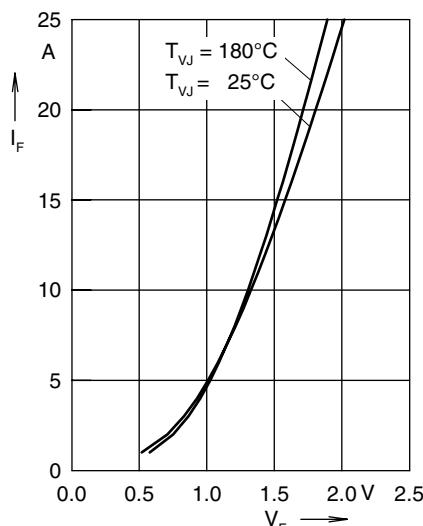


Fig. 1 Forward current versus voltage drop per diode

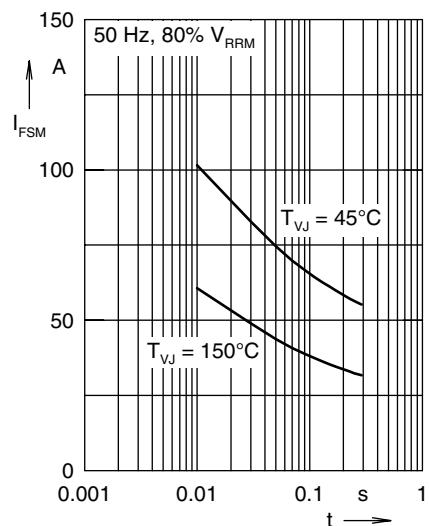


Fig. 2 Surge overload current

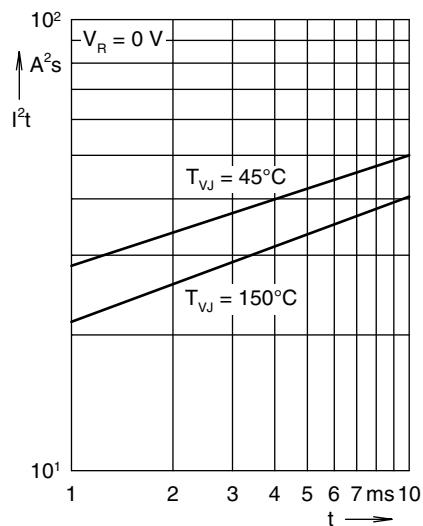


Fig. 3  $I^2t$  versus time per diode

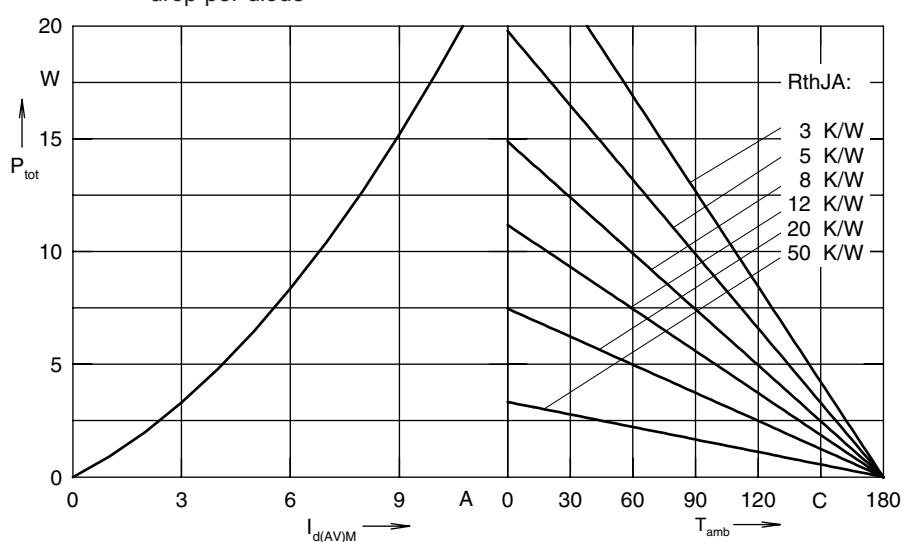


Fig. 4 Power dissipation versus direct output current and ambient temperature, sine 180°

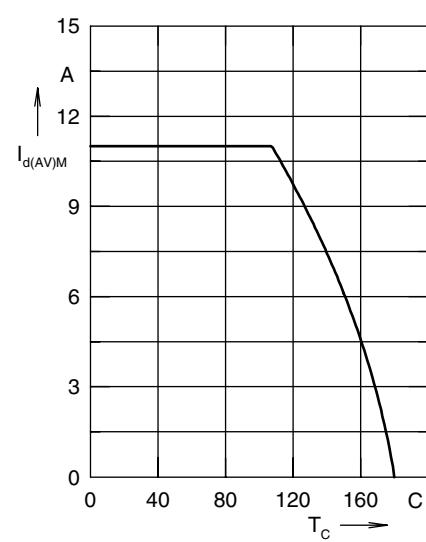


Fig. 5 Max. forward current versus case temperature

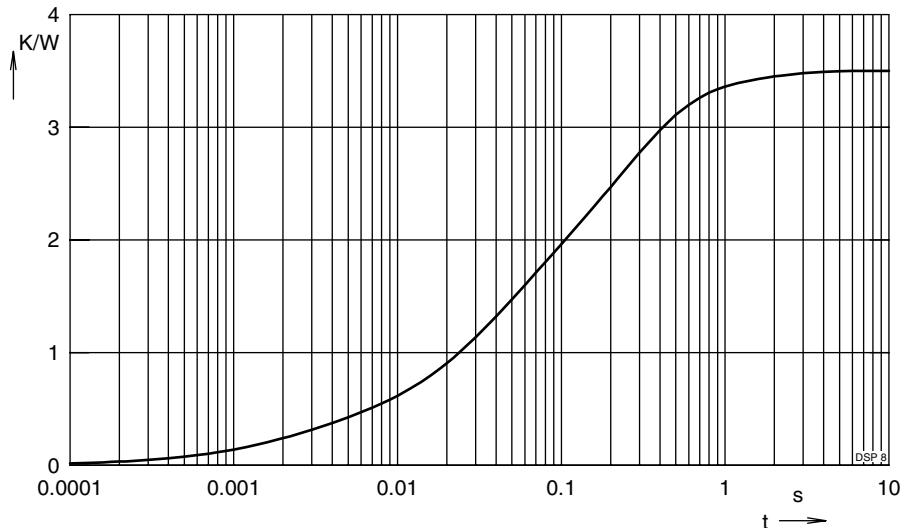


Fig. 6 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.252	0.002
2	1.045	0.032
3	1.932	0.227
4	0.271	1.2